

## LM2717-ADJ Dual Step-Down DC/DC Converter

Check for Samples: [LM2717-ADJ](#)

### FEATURES

- Adjustable Buck Converter with a 2.2A, 0.16 $\Omega$ , Internal Switch (Buck 1)
- Adjustable Buck Converter with a 3.2A, 0.16 $\Omega$ , Internal Switch (Buck 2)
- Operating Input Voltage Range of 4V to 20V
- Input Undervoltage Protection
- 300kHz to 600kHz Pin Adjustable Operating Frequency
- Over Temperature Protection
- Small 24-Lead TSSOP Package

### APPLICATIONS

- TFT-LCD Displays
- Handheld Devices
- Portable Applications
- Laptop Computers
- Automotive Applications

### DESCRIPTION

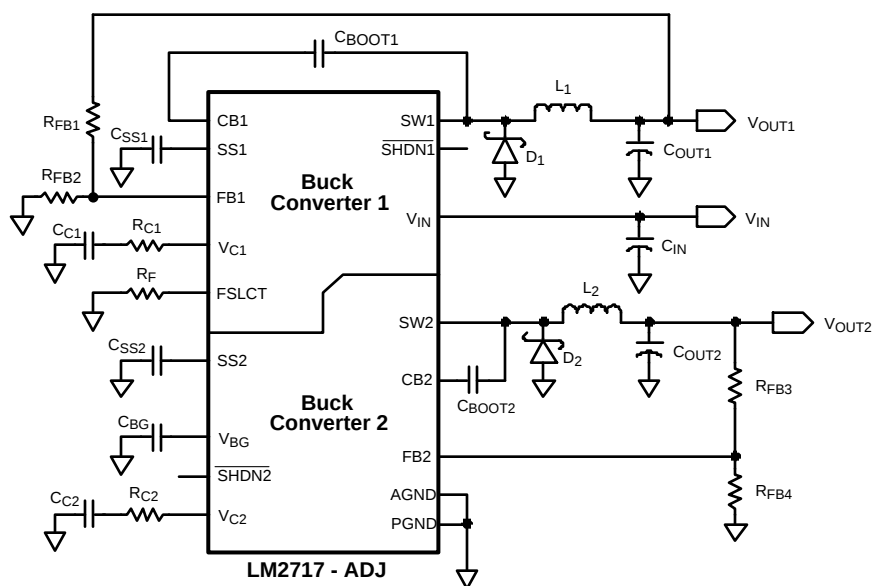
The LM2717-ADJ is composed of two PWM DC/DC buck (step-down) converters. Both converters are used to generate an adjustable output voltage as low as 1.267V. Both also feature low  $R_{DS(on)}$  (0.16 $\Omega$ ) internal switches for maximum efficiency. Operating frequency can be adjusted anywhere between 300kHz and 600kHz allowing the use of small external components. External soft-start pins for each converter enables the user to tailor the soft-start times to a specific application. Each converter may also be shut down independently with its own shutdown pin. The LM2717-ADJ is available in a low profile 24-lead TSSOP package ensuring a low profile overall solution.



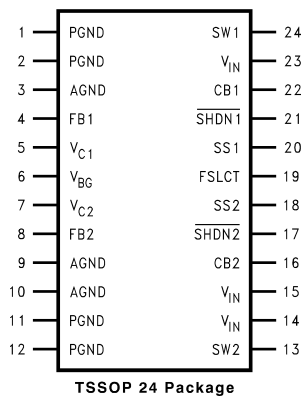
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## Typical Application Circuit



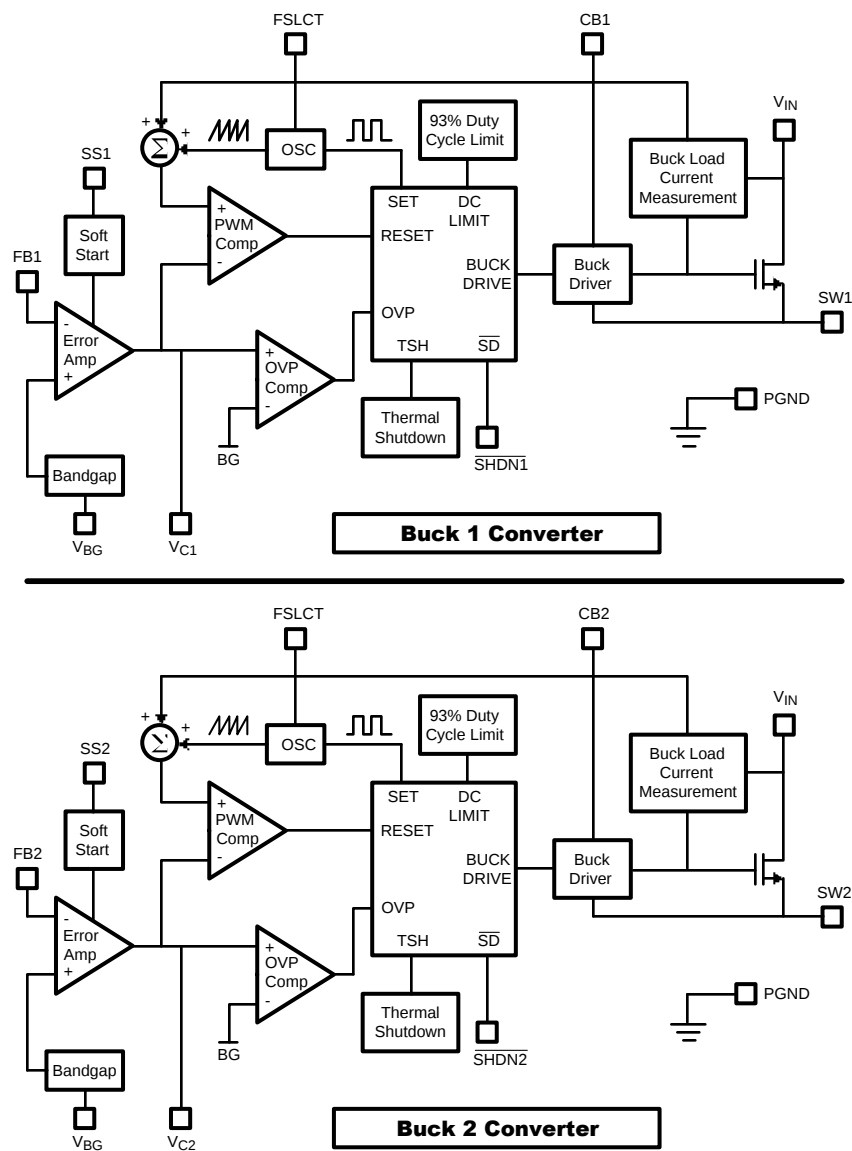
## Connection Diagram



**Figure 1. 24-Lead TSSOP  
Top View**

### PIN DESCRIPTIONS

| Pin | Name                      | Function                                                                                                                     |
|-----|---------------------------|------------------------------------------------------------------------------------------------------------------------------|
| 1   | PGND                      | Power ground. PGND and AGND pins must be connected together directly at the part.                                            |
| 2   | PGND                      | Power ground. PGND and AGND pins must be connected together directly at the part.                                            |
| 3   | AGND                      | Analog ground. PGND and AGND pins must be connected together directly at the part.                                           |
| 4   | FB1                       | Buck 1 output voltage feedback input.                                                                                        |
| 5   | V <sub>C1</sub>           | Buck 1 compensation network connection. Connected to the output of the voltage error amplifier.                              |
| 6   | V <sub>BG</sub>           | Bandgap connection.                                                                                                          |
| 7   | V <sub>C2</sub>           | Buck 2 compensation network connection. Connected to the output of the voltage error amplifier.                              |
| 8   | FB2                       | Buck 2 output voltage feedback input.                                                                                        |
| 9   | AGND                      | Analog ground. PGND and AGND pins must be connected together directly at the part.                                           |
| 10  | AGND                      | Analog ground. PGND and AGND pins must be connected together directly at the part.                                           |
| 11  | PGND                      | Power ground. PGND and AGND pins must be connected together directly at the part.                                            |
| 12  | PGND                      | Power ground. PGND and AGND pins must be connected together directly at the part.                                            |
| 13  | SW2                       | Buck 2 power switch input. Switch connected between V <sub>IN</sub> pins and SW2 pin.                                        |
| 14  | V <sub>IN</sub>           | Analog power input. All V <sub>IN</sub> pins are internally connected and should be connected together directly at the part. |
| 15  | V <sub>IN</sub>           | Analog power input. All V <sub>IN</sub> pins are internally connected and should be connected together directly at the part. |
| 16  | CB2                       | Buck 2 converter bootstrap capacitor connection.                                                                             |
| 17  | $\overline{\text{SHDN2}}$ | Shutdown pin for Buck 2 converter. Active low.                                                                               |
| 18  | SS2                       | Buck 2 soft start pin.                                                                                                       |
| 19  | FSLCT                     | Switching frequency select input. Use a resistor to set the frequency anywhere between 300kHz and 600kHz.                    |
| 20  | SS1                       | Buck 1 soft start pin.                                                                                                       |
| 21  | $\overline{\text{SHDN1}}$ | Shutdown pin for Buck 1 converter. Active low.                                                                               |
| 22  | CB1                       | Buck 1 converter bootstrap capacitor connection.                                                                             |
| 23  | V <sub>IN</sub>           | Analog power input. All V <sub>IN</sub> pins are internally connected and should be connected together directly at the part. |
| 24  | SW1                       | Buck 1 power switch input. Switch connected between V <sub>IN</sub> pins and SW1 pin.                                        |

**Block Diagram**



These devices have limited built-in ESD protection. The leads should be shorted together or the device placed in conductive foam during storage or handling to prevent electrostatic damage to the MOS gates.

## Absolute Maximum Ratings <sup>(1)</sup>

|                                   |                                                                     |
|-----------------------------------|---------------------------------------------------------------------|
| V <sub>IN</sub>                   | –0.3V to 22V                                                        |
| SW1 Voltage                       | –0.3V to 22V                                                        |
| SW2 Voltage                       | –0.3V to 22V                                                        |
| FB1, FB2 Voltages                 | –0.3V to 7V                                                         |
| CB1, CB2 Voltages                 | –0.3V to V <sub>IN</sub> +7V<br>(V <sub>IN</sub> =V <sub>SW</sub> ) |
| V <sub>C1</sub> Voltage           | 1.75V ≤ V <sub>C1</sub> ≤ 2.25V                                     |
| V <sub>C2</sub> Voltage           | 0.965V ≤ V <sub>C2</sub> ≤ 1.565V                                   |
| SHDN1 Voltage                     | –0.3V to 7.5V                                                       |
| SHDN2 Voltage                     | –0.3V to 7.5V                                                       |
| SS1 Voltage                       | –0.3V to 2.1V                                                       |
| SS2 Voltage                       | –0.3V to 2.1V                                                       |
| FSLCT Voltage                     | AGND to 5V                                                          |
| Maximum Junction Temperature      | 150°C                                                               |
| Power Dissipation <sup>(2)</sup>  | Internally Limited                                                  |
| Lead Temperature                  | 300°C                                                               |
| Vapor Phase (60 sec.)             | 215°C                                                               |
| Infrared (15 sec.)                | 220°C                                                               |
| ESD Susceptibility <sup>(3)</sup> | Human Body Model                                                    |
|                                   | 2kV                                                                 |

- (1) Absolute maximum ratings are limits beyond which damage to the device may occur. Operating Ratings are conditions for which the device is intended to be functional, but device parameter specifications may not be ensured. For ensured specifications and test conditions, see the Electrical Characteristics table.
- (2) The maximum allowable power dissipation is a function of the maximum junction temperature, T<sub>J</sub>(MAX), the junction-to-ambient thermal resistance, θ<sub>JA</sub>, and the ambient temperature, T<sub>A</sub>. See the Electrical Characteristics table for the thermal resistance. The maximum allowable power dissipation at any ambient temperature is calculated using: P<sub>D</sub> (MAX) = (T<sub>J</sub>(MAX) – T<sub>A</sub>)/θ<sub>JA</sub>. Exceeding the maximum allowable power dissipation will cause excessive die temperature, and the regulator will go into thermal shutdown.
- (3) The human body model is a 100 pF capacitor discharged through a 1.5kΩ resistor into each pin.

## Operating Conditions

|                                                     |                  |
|-----------------------------------------------------|------------------|
| Operating Junction Temperature Range <sup>(1)</sup> | –40°C to +125°C  |
| Storage Temperature                                 | –65°C to +150°C  |
| Supply Voltage                                      | 4V to 20V        |
| SW1 Voltage                                         | 20V              |
| SW2 Voltage                                         | 20V              |
| Switching Frequency                                 | 300kHz to 600kHz |

- (1) All limits specified at room temperature (standard typeface) and at temperature extremes (bold typeface). All room temperature limits are 100% tested or specified through statistical analysis. All limits at temperature extremes are specified via correlation using standard Statistical Quality Control (SQC) methods. All limits are used to calculate Average Outgoing Quality Level (AOQL).

## Electrical Characteristics

Specifications in standard type face are for  $T_J = 25^\circ\text{C}$  and those with **boldface type** apply over the full **Operating Temperature Range** ( $T_J = -40^\circ\text{C}$  to  $+125^\circ\text{C}$ ).  $V_{IN} = 5\text{V}$ ,  $I_L = 0\text{A}$ , and  $F_{SW} = 300\text{kHz}$  unless otherwise specified.

| Symbol                   | Parameter                                | Conditions                                      | Min<br>(1)            | Typ<br>(2) | Max<br>(1)            | Units           |
|--------------------------|------------------------------------------|-------------------------------------------------|-----------------------|------------|-----------------------|-----------------|
| $I_Q$                    | Total Quiescent Current (both switchers) | Not Switching                                   |                       | 2.7        | <b>6</b>              | mA              |
|                          |                                          | Switching, switch open                          |                       | 6          | <b>12</b>             | mA              |
|                          |                                          | $\overline{V_{SHDN}} = 0\text{V}$               |                       | 9          | <b>27</b>             | $\mu\text{A}$   |
| $V_{BG}$                 | Bandgap Voltage                          |                                                 | 1.248<br><b>1.230</b> | 1.267      | 1.294<br><b>1.299</b> | V               |
| $\%V_{BG}/\Delta V_{IN}$ | Bandgap Voltage Line Regulation          |                                                 | <b>-0.01</b>          |            | 0.01<br><b>0.125</b>  | %/V             |
| $V_{FB1}$                | Buck 1 Feedback Voltage                  |                                                 | 1.236<br><b>1.214</b> | 1.258      | 1.286<br><b>1.288</b> | V               |
| $V_{FB2}$                | Buck 2 Feedback Voltage                  |                                                 | 1.236<br><b>1.214</b> | 1.258      | 1.286<br><b>1.288</b> | V               |
| $I_{CL1}^{(3)}$          | Buck 1 Switch Current Limit              | $V_{IN} = 8\text{V}^{(4)}$                      |                       | 2.2        |                       | A               |
|                          |                                          | $V_{IN} = 12\text{V}$ , $V_{OUT} = 3.3\text{V}$ | 1.4                   | 1.65       | 2.0                   |                 |
| $I_{CL2}^{(3)}$          | Buck 2 Switch Current Limit              | $V_{IN} = 8\text{V}^{(4)}$                      |                       | 3.2        |                       | A               |
|                          |                                          | $V_{IN} = 12\text{V}$ , $V_{OUT} = 5\text{V}$   | 2.6                   | 3.05       | 3.5                   |                 |
| $I_{B1}$                 | Buck 1 FB Pin Bias Current<br>(5)        | $V_{IN} = 20\text{V}$                           |                       | 70         | <b>400</b>            | nA              |
| $I_{B2}$                 | Buck 2 FB Pin Bias Current<br>(5)        | $V_{IN} = 20\text{V}$                           |                       | 65         | <b>400</b>            | nA              |
| $V_{IN}$                 | Input Voltage Range                      |                                                 | <b>4</b>              |            | <b>20</b>             | V               |
| $g_{m1}$                 | Buck 1 Error Amp Transconductance        | $\Delta I = 20\mu\text{A}$                      |                       | 1340       |                       | $\mu\text{mho}$ |
| $g_{m2}$                 | Buck 2 Error Amp Transconductance        | $\Delta I = 20\mu\text{A}$                      |                       | 1360       |                       | $\mu\text{mho}$ |
| $A_{V1}$                 | Buck 1 Error Amp Voltage Gain            |                                                 |                       | 134        |                       | V/V             |
| $A_{V2}$                 | Buck 2 Error Amp Voltage Gain            |                                                 |                       | 136        |                       | V/V             |
| $D_{MAX}$                | Maximum Duty Cycle                       |                                                 | <b>89</b>             | 93         |                       | %               |
| $F_{SW}$                 | Switching Frequency                      | $R_F = 46.4\text{k}$                            | <b>240</b>            | 300        | <b>360</b>            | kHz             |
|                          |                                          | $R_F = 22.6\text{k}$                            | <b>480</b>            | 600        | <b>720</b>            | kHz             |
| $I_{SHDN1}$              | Buck 1 Shutdown Pin Current              | $0\text{V} < V_{SHDN1} < 7.5\text{V}$           | <b>-5</b>             |            | <b>5</b>              | $\mu\text{A}$   |
| $I_{SHDN2}$              | Buck 2 Shutdown Pin Current              | $0\text{V} < V_{SHDN2} < 7.5\text{V}$           | <b>-5</b>             |            | <b>5</b>              | $\mu\text{A}$   |
| $I_{L1}$                 | Buck 1 Switch Leakage Current            | $V_{IN} = 20\text{V}$                           |                       | 0.01       | <b>5</b>              | $\mu\text{A}$   |
| $I_{L2}$                 | Buck 2 Switch Leakage Current            | $V_{IN} = 20\text{V}$                           |                       | 0.01       | <b>5</b>              | $\mu\text{A}$   |
| $R_{DSON1}$              | Buck 1 Switch $R_{DSON}^{(6)}$           | $I_{SW} = 100\text{mA}$                         |                       | 160        | 180<br><b>300</b>     | m $\Omega$      |
| $R_{DSON2}$              | Buck 2 Switch $R_{DSON}^{(6)}$           | $I_{SW} = 100\text{mA}$                         |                       | 160        | 180<br><b>300</b>     | m $\Omega$      |
| $Th_{SHDN1}$             | Buck 1 $\overline{SHDN}$ Threshold       | Output High                                     | <b>1.8</b>            | 1.36       |                       | V               |
|                          |                                          | Output Low                                      |                       | 1.33       | <b>0.7</b>            |                 |

(1) All limits specified at room temperature (standard typeface) and at temperature extremes (bold typeface). All room temperature limits are 100% tested or specified through statistical analysis. All limits at temperature extremes are specified via correlation using standard Statistical Quality Control (SQC) methods. All limits are used to calculate Average Outgoing Quality Level (AOQL).

(2) Typical numbers are at  $25^\circ\text{C}$  and represent the most likely norm.

(3) Duty cycle affects current limit due to ramp generator.

(4) Current limit at 0% duty cycle. See [TYPICAL PERFORMANCE](#) section for Switch Current Limit vs. Input Voltage.

(5) Bias current flows into FB pin.

(6) Includes the bond wires and package leads,  $R_{DSON}$  from  $V_{IN}$  pin(s) to SW pin.

## Electrical Characteristics (continued)

Specifications in standard type face are for  $T_J = 25^{\circ}\text{C}$  and those with **boldface type** apply over the full **Operating Temperature Range** ( $T_J = -40^{\circ}\text{C}$  to  $+125^{\circ}\text{C}$ ).  $V_{IN} = 5\text{V}$ ,  $I_L = 0\text{A}$ , and  $F_{SW} = 300\text{kHz}$  unless otherwise specified.

| Symbol                                | Parameter                                 | Conditions          | Min<br>(1) | Typ<br>(2) | Max<br>(1) | Units                |
|---------------------------------------|-------------------------------------------|---------------------|------------|------------|------------|----------------------|
| $\overline{\text{Th}}_{\text{SHDN2}}$ | Buck 2 $\overline{\text{SHDN}}$ Threshold | Output High         | <b>1.8</b> | 1.36       |            | V                    |
|                                       |                                           | Output Low          |            | 1.33       | <b>0.7</b> |                      |
| $I_{\text{SS1}}$                      | Buck 1 Soft Start Pin Current             |                     | <b>4</b>   | 9          | <b>15</b>  | $\mu\text{A}$        |
| $I_{\text{SS2}}$                      | Buck 2 Soft Start Pin Current             |                     | <b>4</b>   | 9          | <b>15</b>  | $\mu\text{A}$        |
| UVP                                   | On Threshold                              |                     | <b>4</b>   | 3.8        |            | V                    |
|                                       | Off Threshold                             |                     |            | 3.6        | <b>3.3</b> |                      |
| $\theta_{\text{JA}}$                  | Thermal Resistance<br>(7)                 | TSSOP, package only |            | 115        |            | $^{\circ}\text{C/W}$ |

(7) Refer to the [www.ti.com/packaging](http://www.ti.com/packaging) for more detailed thermal information and mounting techniques for the TSSOP package.

## Typical Performance Characteristics

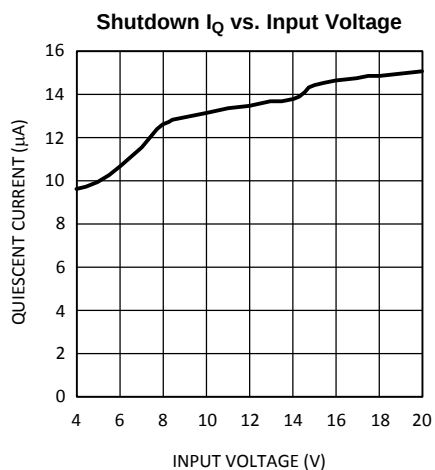


Figure 2.

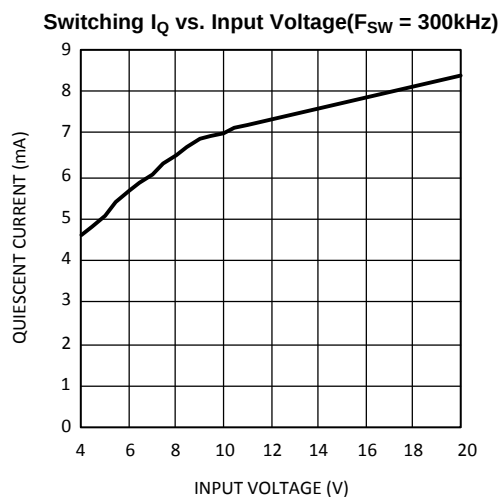


Figure 3.

**Switching Frequency vs. Input Voltage ( $F_{SW} = 300\text{kHz}$ )**

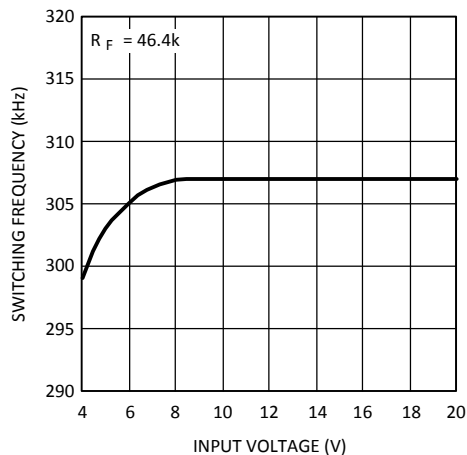


Figure 4.

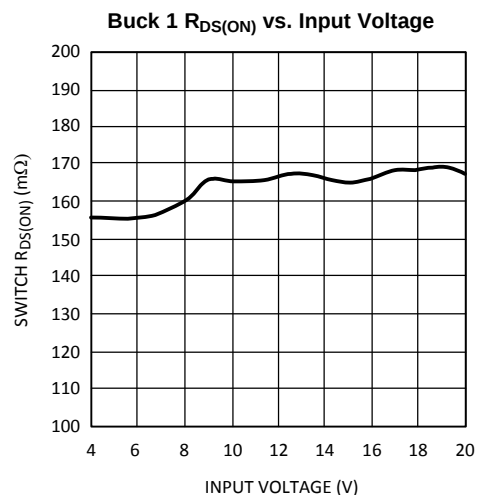


Figure 5.

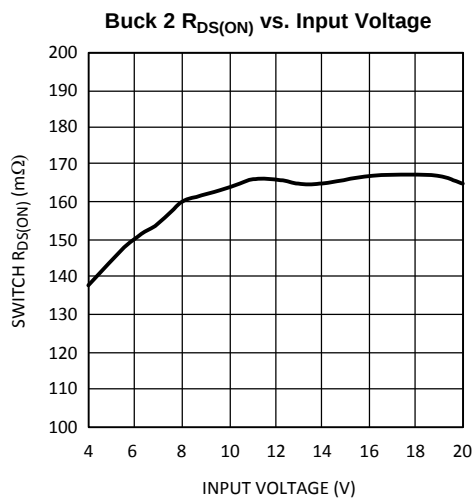


Figure 6.

**Buck 1 Efficiency vs. Load Current ( $V_{OUT} = 3.3\text{V}$ )**

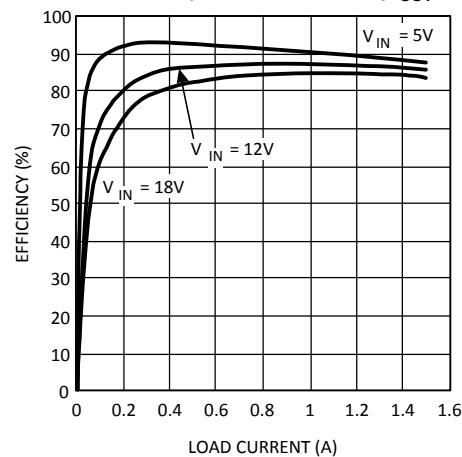
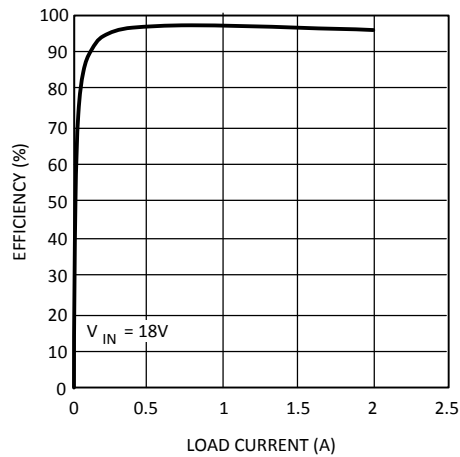


Figure 7.

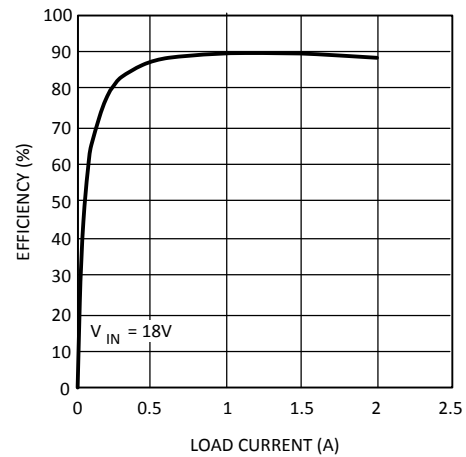
## Typical Performance Characteristics (continued)

**Buck 2 Efficiency vs. Load Current( $V_{OUT} = 15V$ )**



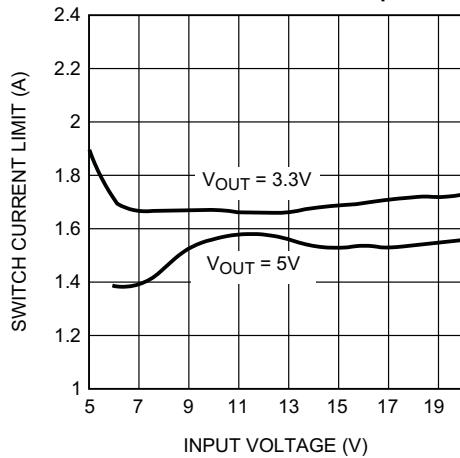
**Figure 8.**

**Buck 2 Efficiency vs. Load Current( $V_{OUT} = 5V$ )**



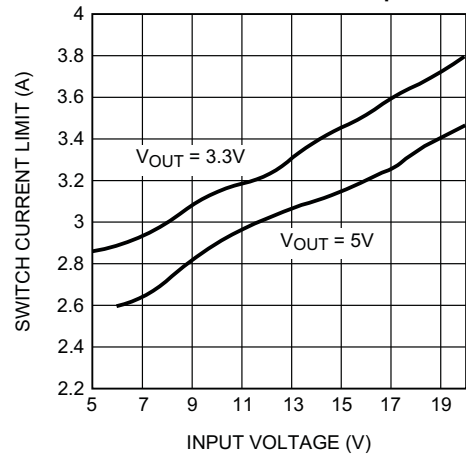
**Figure 9.**

**Buck 1 Switch Current Limit vs. Input Voltage**



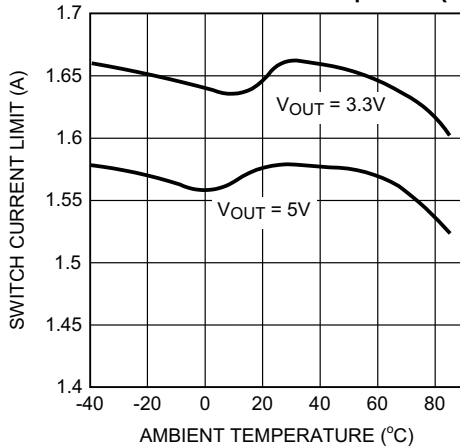
**Figure 10.**

**Buck 2 Switch Current Limit vs. Input Voltage**



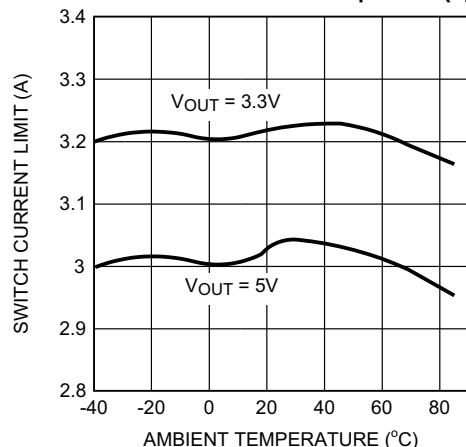
**Figure 11.**

**Buck 1 Switch Current Limit vs. Temperature( $V_{IN} = 12V$ )**



**Figure 12.**

**Buck 2 Switch Current Limit vs. Temperature( $V_{IN} = 12V$ )**



**Figure 13.**

### Typical Performance Characteristics (continued)

Buck 1 Switch ON Resistance vs. Temperature

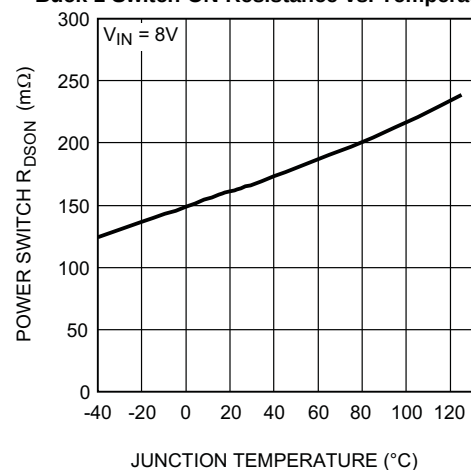


Figure 14.

Buck 2 Switch ON Resistance vs. Temperature

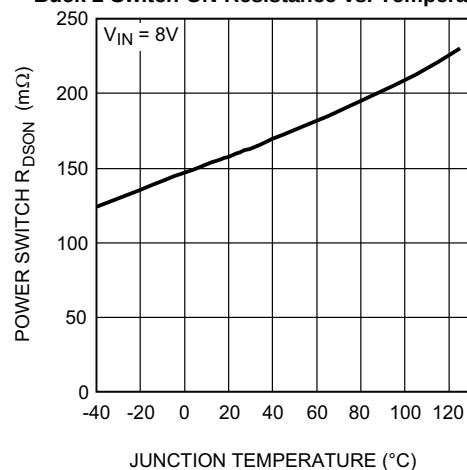


Figure 15.

Switching Frequency vs.  $R_F$  Resistance

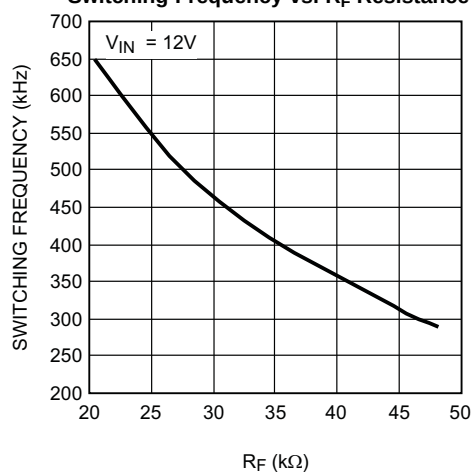


Figure 16.

## BUCK OPERATION

### PROTECTION (BOTH REGULATORS)

The LM2717-ADJ has dedicated protection circuitry running during normal operation to protect the IC. The Thermal Shutdown circuitry turns off the power devices when the die temperature reaches excessive levels. The UVP comparator protects the power devices during supply power startup and shutdown to prevent operation at voltages less than the minimum input voltage. The OVP comparator is used to prevent the output voltage from rising at no loads allowing full PWM operation over all load conditions. The LM2717-ADJ also features a shutdown mode for each converter decreasing the supply current to approximately 10µA (both in shutdown mode).

### CONTINUOUS CONDUCTION MODE

The LM2717-ADJ contains current-mode, PWM buck regulators. A buck regulator steps the input voltage down to a lower output voltage. In continuous conduction mode (when the inductor current never reaches zero at steady state), the buck regulator operates in two cycles. The power switch is connected between  $V_{IN}$  and SW1 and SW2.

In the first cycle of operation the transistor is closed and the diode is reverse biased. Energy is collected in the inductor and the load current is supplied by  $C_{OUT}$  and the rising current through the inductor.

During the second cycle the transistor is open and the diode is forward biased due to the fact that the inductor current cannot instantaneously change direction. The energy stored in the inductor is transferred to the load and output capacitor.

The ratio of these two cycles determines the output voltage. The output voltage is defined approximately as:

$$D = \frac{V_{OUT}}{V_{IN}}, D' = (1-D)$$

where

- where D is the duty cycle of the switch
  - D and D' will be required for design calculation
- (1)

The LM2717-ADJ has a minimum switch ON time which corresponds to a minimum duty cycle of approximately 10% at 600kHz operation and approximately 5% at 300kHz operation. In the case of some high voltage differential applications (low duty cycle operation) this minimum duty cycle may be exceeded causing the feedback pin over-voltage protection to trip as the output voltage rises. This will put the device into a PFM type operation which can cause an unpredictable frequency spectrum and may cause the average output voltage to rise slightly. If this is a concern the switching frequency may be lowered and/or a pre-load added to the output to keep the device full PWM operation. Note that the OVP function monitors the FB pin so it will not function if the feedback resistor is disconnected from the output. Due to slight differences between the two converters it is recommended that Buck 1 be used for the lower of the two output voltages for best operation.

### DESIGN PROCEDURE

This section presents guidelines for selecting external components.

### SETTING THE OUTPUT VOLTAGE

The output voltage is set using the feedback pin and a resistor divider connected to the output as shown in [Figure 20](#). The feedback pin voltage ( $V_{FB}$ ) is 1.258V, so the ratio of the feedback resistors sets the output voltage according to the following equation:

$$R_{FB1(3)} = R_{FB2(4)} \times \frac{V_{OUT} - V_{FB1(2)}}{V_{FB1(2)}} \Omega$$
(2)

## INPUT CAPACITOR

A low ESR aluminum, tantalum, or ceramic capacitor is needed between the input pin and power ground. This capacitor prevents large voltage transients from appearing at the input. The capacitor is selected based on the RMS current and voltage requirements. The RMS current is given by:

$$I_{RMS} = I_{OUT} \times \frac{\sqrt{V_{OUT}(V_{IN} - V_{OUT})}}{V_{IN}} \quad (3)$$

The RMS current reaches its maximum ( $I_{OUT}/2$ ) when  $V_{IN}$  equals  $2V_{OUT}$ . This value should be calculated for both regulators and added to give a total RMS current rating. For an aluminum or ceramic capacitor, the voltage rating should be at least 25% higher than the maximum input voltage. If a tantalum capacitor is used, the voltage rating required is about twice the maximum input voltage. The tantalum capacitor should be surge current tested by the manufacturer to prevent being shorted by the inrush current. The minimum capacitor value should be  $47\mu\text{F}$  for lower output load current applications and less dynamic (quickly changing) load conditions. For higher output current applications or dynamic load conditions a  $68\mu\text{F}$  to  $100\mu\text{F}$  low ESR capacitor is recommended. It is also recommended to put a small ceramic capacitor ( $0.1\mu\text{F}$  to  $4.7\mu\text{F}$ ) between the input pins and ground to reduce high frequency spikes.

## INDUCTOR SELECTION

The most critical parameter for the inductor in a current mode switcher is the minimum value required for stable operation. To prevent subharmonic oscillations and achieve good phase margin a target minimum value for the inductor is:

$$L_{MIN} = \frac{(D-0.5+2/\pi)(V_{IN}-V_{OUT})R_{DS(on)}}{(1-D)(0.164 \cdot F_{SW})} \quad (\text{H}) \quad (4)$$

Where  $V_{IN}$  is the minimum input voltage and  $R_{DS(on)}$  is the maximum switch ON resistance. For best stability the inductor should be in the range of  $0.5L_{MIN}$  (absolute minimum) and  $2L_{MIN}$ . Using an inductor with a value less than  $0.5L_{MIN}$  can cause subharmonic oscillations. The inductor should meet this minimum requirement at the peak inductor current expected for the application regardless of what the inductor ripple current and output ripple voltage requirements are. A value larger than  $2L_{MIN}$  is acceptable if the ripple requirements of the application require it but it may reduce the phase margin and increase the difficulty in compensating the circuit.

The most important parameters for the inductor from an applications standpoint are the inductance, peak current and the DC resistance. The inductance is related to the peak-to-peak inductor ripple current, the input and the output voltages (for 300kHz operation):

$$L = \frac{(V_{IN} - V_{OUT})V_{OUT}}{V_{IN} \times I_{RIPPLE} \times 300 \text{ kHz}} \quad (5)$$

A higher value of ripple current reduces inductance, but increases the conductance loss, core loss, and current stress for the inductor and switch devices. It also requires a bigger output capacitor for the same output voltage ripple requirement. A reasonable value is setting the ripple current to be 30% of the DC output current. Since the ripple current increases with the input voltage, the maximum input voltage is always used to determine the inductance. The DC resistance of the inductor is a key parameter for the efficiency. Lower DC resistance is available with a bigger winding area. A good tradeoff between the efficiency and the core size is letting the inductor copper loss equal 2% of the output power.

## OUTPUT CAPACITOR

The selection of  $C_{OUT}$  is driven by the maximum allowable output voltage ripple. The output ripple in the constant frequency, PWM mode is approximated by:

$$V_{RIPPLE} = I_{RIPPLE} \left( ESR + \frac{1}{8F_{SC_{OUT}}} \right) \quad (6)$$

The ESR term usually plays the dominant role in determining the voltage ripple. Low ESR ceramic, aluminum electrolytic, or tantalum capacitors (such as MuRata MLCC, Taiyo Yuden MLCC, Nichicon PL series, Sanyo OS-CON, Sprague 593D, 594D, AVX TPS, and CDE polymer aluminum) is recommended. An aluminum electrolytic capacitor is not recommended for temperatures below  $-25^{\circ}\text{C}$  since its ESR rises dramatically at cold temperatures. Ceramic or tantalum capacitors have much better ESR specifications at cold temperature and is preferred for low temperature applications.

## BOOTSTRAP CAPACITOR

A 4.7nF ceramic capacitor or larger is recommended for the bootstrap capacitor. For applications where the input voltage is less than twice the output voltage a larger capacitor is recommended, generally 0.1μF to 1μF to ensure plenty of gate drive for the internal switches and a consistently low  $R_{DS(on)}$ .

## SOFT-START CAPACITOR (BOTH REGULATORS)

The LM2717-ADJ contains circuitry that can be used to limit the inrush current on start-up of the DC/DC switching regulators. This inrush current limiting circuitry serves as a soft-start. The external SS pins are used to tailor the soft-start for a specific application. A current ( $I_{SS}$ ) charges the external soft-start capacitor,  $C_{SS}$ . The soft-start time can be estimated as:

$$T_{SS} = C_{SS} \cdot 0.6V / I_{SS} \quad (7)$$

When programming the soft-start time use the equation given in the *Soft-Start Capacitor* section above. The soft-start function is used simply to limit inrush current to the device that could stress the input voltage supply. The soft-start time described above is the time it takes for the current limit to ramp to maximum value. When this function is used the current limit starts at a low value and increases to nominal at the set soft-start time. Under maximum load conditions the output voltage may rise at the same rate as the soft-start, however at light or no load conditions the output voltage will rise much faster as the switch will not need to conduct much current to charge the output capacitor.

## SHUTDOWN OPERATION (BOTH REGULATORS)

The shutdown pins of the LM2717-ADJ are designed so that they may be controlled using 1.8V or higher logic signals. If the shutdown function is not to be used the pin may be left open. The maximum voltage to the shutdown pin should not exceed 7.5V. If the use of a higher voltage is desired due to system or other constraints it may be used, however a 100k or larger resistor is recommended between the applied voltage and the shutdown pin to protect the device.

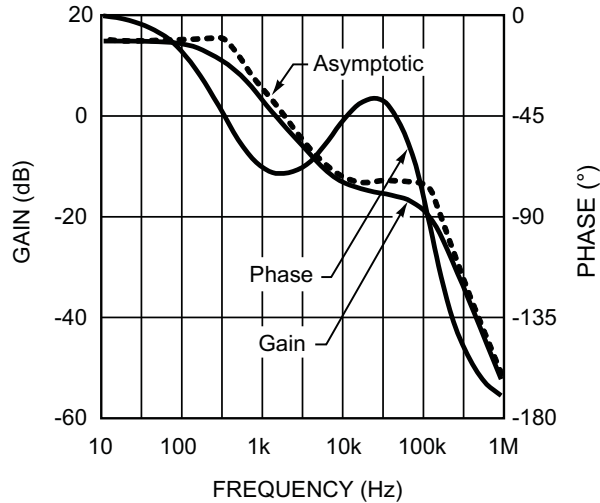
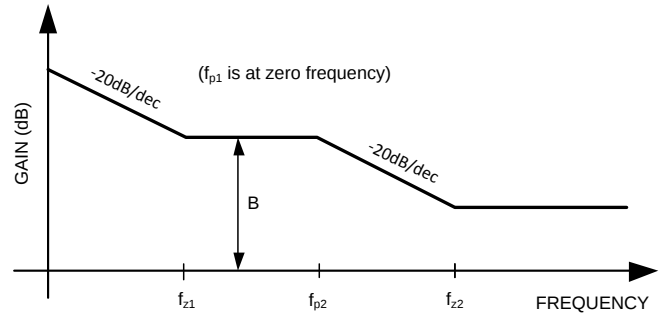
## SCHOTTKY DIODE

The breakdown voltage rating of  $D_1$  and  $D_2$  is preferred to be 25% higher than the maximum input voltage. The current rating for the diode should be equal to the maximum output current for best reliability in most applications. In cases where the input voltage is much greater than the output voltage the average diode current is lower. In this case it is possible to use a diode with a lower average current rating, approximately  $(1-D) \cdot I_{OUT}$  however the peak current rating should be higher than the maximum load current.

## LOOP COMPENSATION

The general purpose of loop compensation is to meet static and dynamic performance requirements while maintaining stability. Loop gain is what is usually checked to determine small-signal performance. Loop gain is equal to the product of control-output transfer function and the output-control transfer function (the compensation network transfer function). The DC loop gain of the LM2717 is usually around 55dB to 60dB when loaded. Generally speaking it is a good idea to have a loop gain slope that is -20dB /decade from a very low frequency to well beyond the crossover frequency. The crossover frequency should not exceed one-fifth of the switching frequency, i.e. 60kHz in the case of 300kHz switching frequency. The higher the bandwidth is, the faster the load transient response speed will potentially be. However, if the duty cycle saturates during a load transient, further increasing the small signal bandwidth will not help. Since the control-output transfer function usually has very limited low frequency gain, it is a good idea to place a pole in the compensation at zero frequency, so that the low frequency gain will be relatively large. A large DC gain means high DC regulation accuracy (i.e. DC voltage changes little with load or line variations). The rest of the compensation scheme depends highly on the shape of the control-output plot.

As shown in [Figure 17](#), the example control-output transfer function consists of one pole ( $f_p$ ), one zero ( $f_z$ ), and a double pole at  $f_n$  (half the switching frequency). The following can be done to create a -20dB /decade roll-off of the loop gain: Place the first pole at 0Hz, the first zero at  $f_p$ , the second pole at  $f_z$ , and the second zero at  $f_n$ . The resulting output-control transfer function is shown in [Figure 18](#).

**Figure 17. Control-Output Transfer Function****Figure 18. Output-Control Transfer Function**

The control-output corner frequencies, and thus the desired compensation corner frequencies, can be determined approximately by the following equations:

$$f_z = \frac{1}{2\pi R_e C_o}$$

where

- $C_o$  is the output capacitance
- $R_e$  is the output capacitance ESR
- $f$  is the switching frequency

(8)

$$f_p = \frac{1}{2\pi R_o C_o} + \frac{.5}{2\pi L f C_o}$$

where

- $C_o$  is the output capacitance
- $R_o$  is the load resistance
- $f$  is the switching frequency

(9)

Since  $f_p$  is determined by the output network, it will shift with loading ( $R_o$ ) and duty cycle. First determine the range of frequencies ( $f_{pmin}/f_{pmax}$ ) of the pole across the expected load range, then place the first compensation zero within that range.

Example:  $V_o = 5V$ ,  $R_e = 20m\Omega$ ,  $C_o = 100\mu F$ ,  $R_{o_{max}} = 5V/100mA = 50\Omega$ ,  $R_{o_{min}} = 5V/1A = 5\Omega$ ,  $L = 10\mu H$ ,  $f = 300kHz$ :

$$f_z = \frac{1}{2\pi \cdot 20 m\Omega \cdot 100 \mu F} = 80 kHz \quad (10)$$

$$f_{p_{min}} = \frac{1}{2\pi \cdot 50\Omega \cdot 100 \mu F} + \frac{0.5}{2\pi \cdot 300k \cdot 10\mu \cdot 100 \mu F} = 297 Hz \quad (11)$$

$$f_{p_{max}} = \frac{1}{2\pi \cdot 5\Omega \cdot 100 \mu F} + \frac{0.5}{2\pi \cdot 300k \cdot 10\mu \cdot 100 \mu F} = 584 Hz \quad (12)$$

Once the  $f_p$  range is determined,  $R_{c1}$  should be calculated using:

$$R_{c1} = \frac{B}{g_m} \left( \frac{R_1 + R_2}{R_1} \right)$$

where

- B is the desired gain in V/V at  $f_p$  (fz1)
- $g_m$  is the transconductance of the error amplifier
- $R_1$  and  $R_2$  are the feedback resistors as shown in [Figure 19](#)

(13)

A gain value around 10dB (3.3v/v) is generally a good starting point.

Example:  $B = 3.3 \text{ v/v}$ ,  $g_m = 1350 \mu\text{mho}$ ,  $R_1 = 20 \text{ K}\Omega$ ,  $R_2 = 59 \text{ K}\Omega$ :

$$R_{c1} = \frac{3.3}{1350 \mu} \cdot \frac{20\text{k} + 59\text{k}}{20\text{k}} \approx 9.76\text{k}$$

(14)

Bandwidth will vary proportional to the value of  $R_{c1}$ . Next,  $C_{c1}$  can be determined with the following equation:

$$C_{c1} = \frac{1}{2\pi \cdot f_p \cdot R_{c1}}$$

(15)

Example:  $f_{pmin} = 297 \text{ Hz}$ ,  $R_{c1} = 20 \text{ K}\Omega$ :

$$C_{c1} = \frac{1}{2\pi \cdot 297 \text{ Hz} \cdot 9.76\text{k}} \approx 56 \text{ nF}$$

(16)

The value of  $C_{c1}$  should be within the range determined by  $f_{pmin}/\text{max}$ . A higher value will generally provide a more stable loop, but too high a value will slow the transient response time.

The compensation network ([Figure 19](#)) will also introduce a low frequency pole which will be close to 0Hz.

A second pole should also be placed at  $f_z$ . This pole can be created with a single capacitor  $C_{c2}$  and a shorted  $R_{c2}$  (see [Figure 19](#)). The minimum value for this capacitor can be calculated by:

$$C_{c2 \text{ min}} = \frac{1}{2\pi \cdot f_z \cdot R_{c1}}$$

(17)

$C_{c2}$  may not be necessary, however it does create a more stable control loop. This is especially important with high load currents.

Example:  $f_z = 80 \text{ kHz}$ ,  $R_{c1} = 20 \text{ K}\Omega$ :

$$C_{c2 \text{ min}} = \frac{1}{2\pi \cdot 80 \text{ kHz} \cdot 20 \text{ k}\Omega} \cong 100 \text{ pF}$$

(18)

A second zero can also be added with a resistor in series with  $C_{c2}$ . If used, this zero should be placed at  $f_n$ , where the control to output gain rolls off at -40dB/dec. Generally,  $f_n$  will be well below the 0dB level and thus will have little effect on stability.  $R_{c2}$  can be calculated with the following equation:

$$R_{c2} = \frac{1}{2\pi \cdot f_n \cdot C_{c2}}$$

(19)

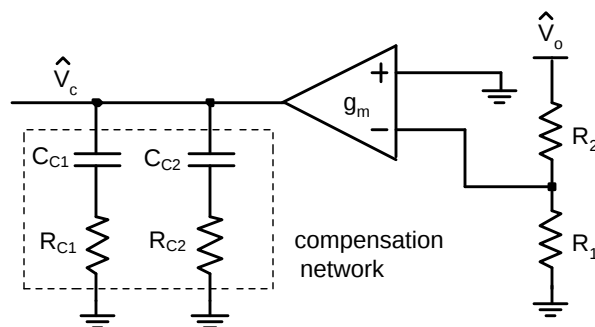


Figure 19. Compensation Network

Note that the values calculated here give a good baseline for stability and will work well with most applications. The values in some cases may need to be adjusted some for optimum stability or the values may need to be adjusted depending on a particular applications bandwidth requirements.

## LAYOUT CONSIDERATIONS

The LM2717-ADJ uses two separate ground connections, PGND for the drivers and boost NMOS power device and AGND for the sensitive analog control circuitry. The AGND and PGND pins should be tied directly together at the package. The feedback and compensation networks should be connected directly to a dedicated analog ground plane and this ground plane must connect to the AGND pin. If no analog ground plane is available then the ground connections of the feedback and compensation networks must tie directly to the AGND pin. Connecting these networks to the PGND can inject noise into the system and effect performance.

The input bypass capacitor  $C_{IN}$ , as shown in [Figure 20](#), must be placed close to the IC. This will reduce copper trace resistance which effects input voltage ripple of the IC. For additional input voltage filtering, a 0.1 $\mu$ F to 4.7 $\mu$ F bypass capacitors can be placed in parallel with  $C_{IN}$ , close to the  $V_{IN}$  pins to shunt any high frequency noise to ground. The output capacitors,  $C_{OUT1}$  and  $C_{OUT2}$ , should also be placed close to the IC. Any copper trace connections for the  $C_{OUTX}$  capacitors can increase the series resistance, which directly effects output voltage ripple. The feedback network, resistors  $R_{FB1(3)}$  and  $R_{FB2(4)}$ , should be kept close to the FB pin, and away from the inductor to minimize copper trace connections that can inject noise into the system. Trace connections made to the inductors and schottky diodes should be minimized to reduce power dissipation and increase overall efficiency. For more detail on switching power supply layout considerations see Application Note AN-1149: *Layout Guidelines for Switching Power Supplies* ([SNVA021](#)).

## APPLICATION INFORMATION

**Table 1. Some Recommended Inductors (Others May Be Used)**

| Manufacturer | Inductor                     | Contact Information                                                              |
|--------------|------------------------------|----------------------------------------------------------------------------------|
| Coilcraft    | DO3316 and DT3316 series     | <a href="http://www.coilcraft.com">www.coilcraft.com</a><br>800-3222645          |
| TDK          | SLF10145 series              | <a href="http://www.component.tdk.com">www.component.tdk.com</a><br>847-803-6100 |
| Pulse        | P0751 and P0762 series       | <a href="http://www.pulseeng.com">www.pulseeng.com</a>                           |
| Sumida       | CDRH8D28 and CDRH8D43 series | <a href="http://www.sumida.com">www.sumida.com</a>                               |

**Table 2. Some Recommended Input And Output Capacitors (Others May Be Used)**

| Manufacturer     | Capacitor                                                                     | Contact Information                                  |
|------------------|-------------------------------------------------------------------------------|------------------------------------------------------|
| Vishay Sprague   | 293D, 592D, and 595D series tantalum                                          | <a href="http://www.vishay.com">www.vishay.com</a>   |
| Taiyo Yuden      | High capacitance MLCC ceramic                                                 | <a href="http://www.t-yuden.com">www.t-yuden.com</a> |
| Cornell Dubilier | ESRD seriec Polymer Aluminum Electrolytic<br>SPV and AFK series V-chip series | <a href="http://www.cde.com">www.cde.com</a>         |
| MuRata           | High capacitance MLCC ceramic                                                 | <a href="http://www.murata.com">www.murata.com</a>   |

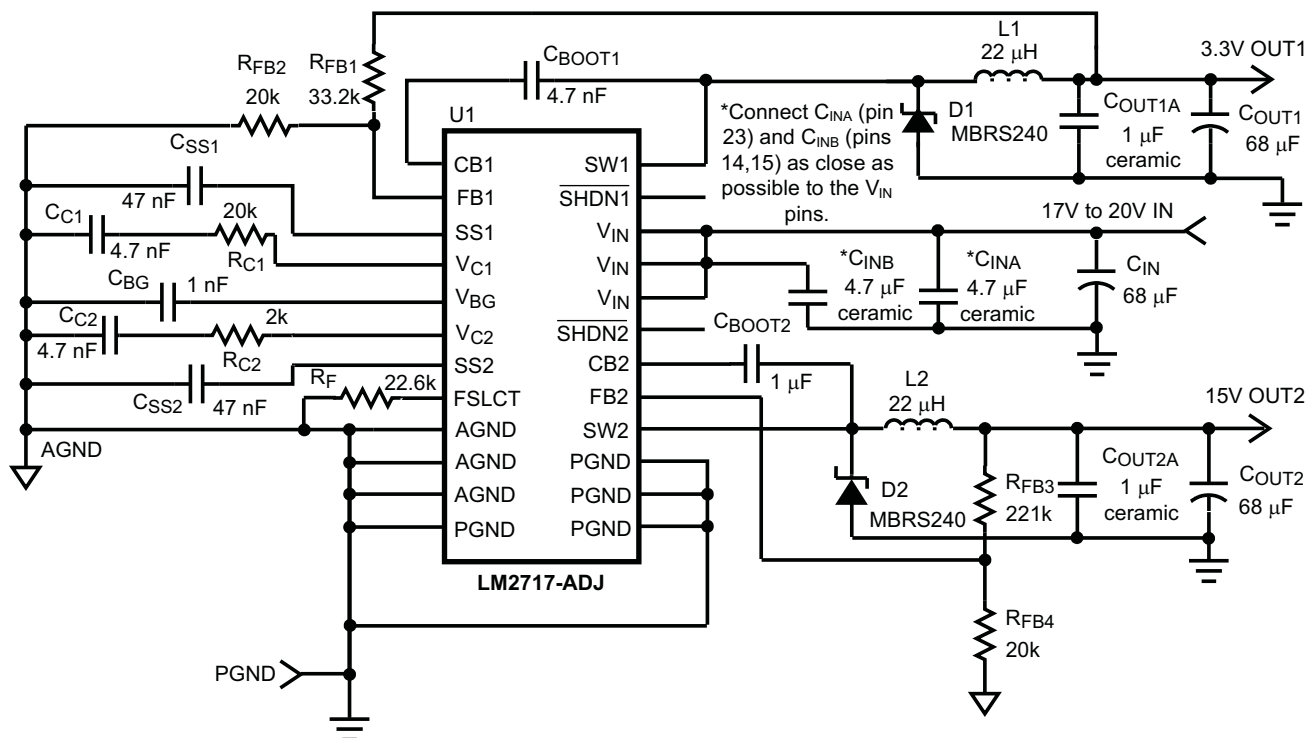


Figure 20. 15V, 3.3V Output Application

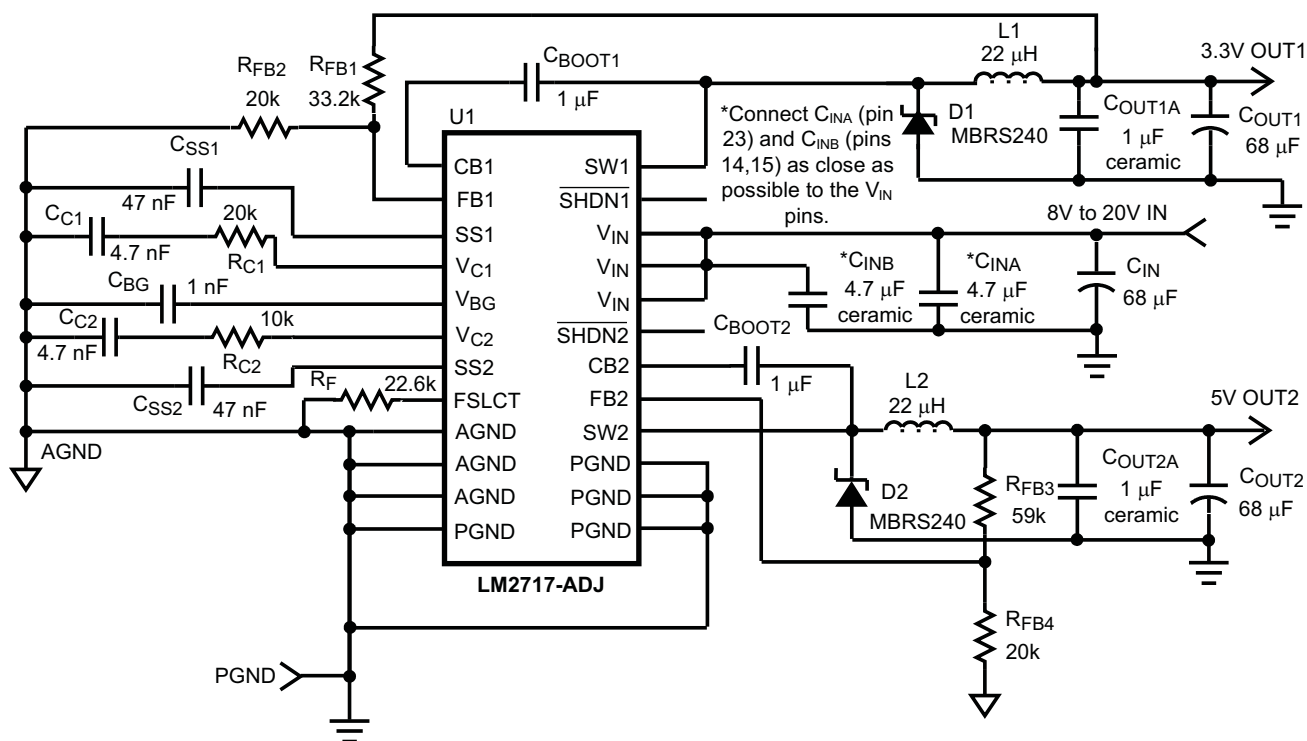


Figure 21. 5V, 3.3V Output Application

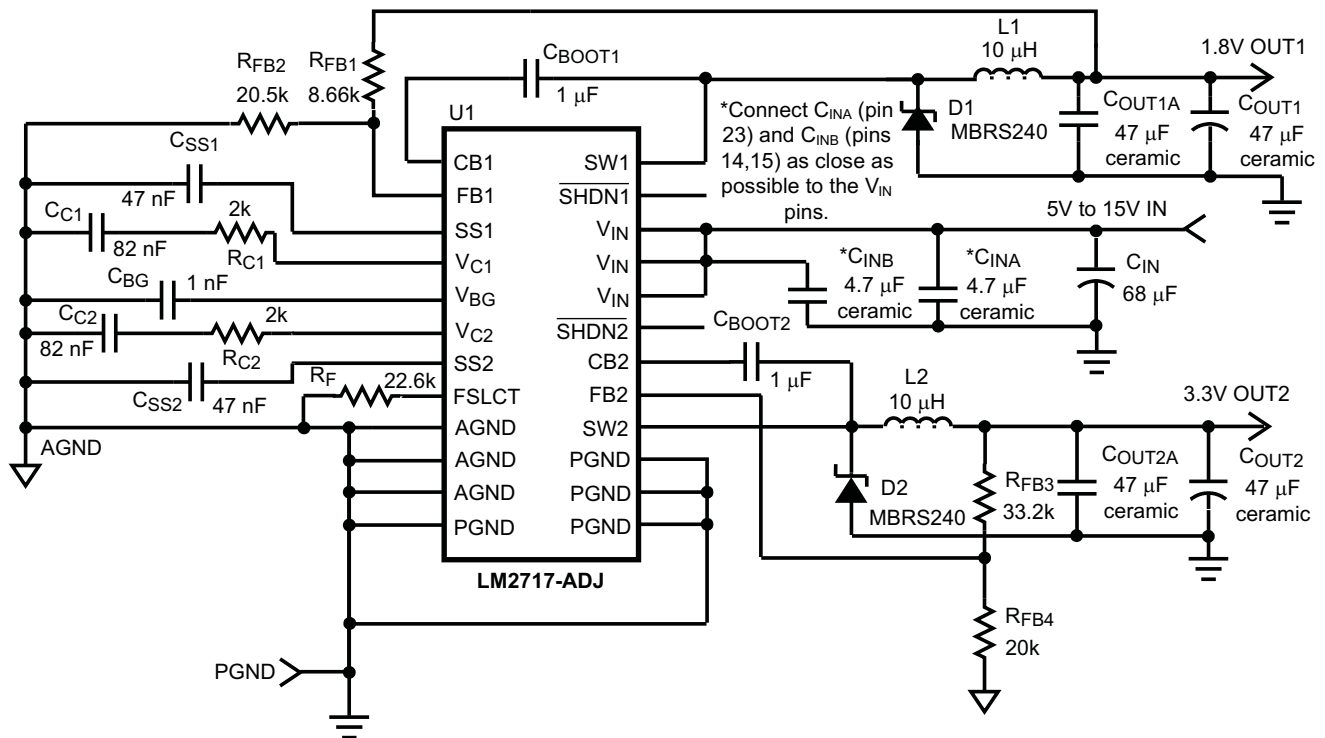


Figure 22. 3.3V, 1.8V Output Application

## REVISION HISTORY

| Changes from Revision B (March 2013) to Revision C         | Page               |
|------------------------------------------------------------|--------------------|
| • Changed layout of National Data Sheet to TI format ..... | <a href="#">18</a> |

## PACKAGING INFORMATION

| Orderable Device   | Status<br>(1) | Package Type | Package<br>Drawing | Pins | Package<br>Qty | Eco Plan<br>(2) | Lead finish/<br>Ball material<br>(6) | MSL Peak Temp<br>(3) | Op Temp (°C) | Device Marking<br>(4/5) | Samples                 |
|--------------------|---------------|--------------|--------------------|------|----------------|-----------------|--------------------------------------|----------------------|--------------|-------------------------|-------------------------|
| LM2717MT-ADJ/NOPB  | ACTIVE        | TSSOP        | PW                 | 24   | 61             | RoHS & Green    | SN                                   | Level-1-260C-UNLIM   | -40 to 125   | LM2717<br>MT-ADJ        | <a href="#">Samples</a> |
| LM2717MTX-ADJ/NOPB | ACTIVE        | TSSOP        | PW                 | 24   | 2500           | RoHS & Green    | SN                                   | Level-1-260C-UNLIM   | -40 to 125   | LM2717<br>MT-ADJ        | <a href="#">Samples</a> |

(1) The marketing status values are defined as follows:

**ACTIVE:** Product device recommended for new designs.

**LIFEBUY:** TI has announced that the device will be discontinued, and a lifetime-buy period is in effect.

**NRND:** Not recommended for new designs. Device is in production to support existing customers, but TI does not recommend using this part in a new design.

**PREVIEW:** Device has been announced but is not in production. Samples may or may not be available.

**OBSOLETE:** TI has discontinued the production of the device.

(2) **RoHS:** TI defines "RoHS" to mean semiconductor products that are compliant with the current EU RoHS requirements for all 10 RoHS substances, including the requirement that RoHS substance do not exceed 0.1% by weight in homogeneous materials. Where designed to be soldered at high temperatures, "RoHS" products are suitable for use in specified lead-free processes. TI may reference these types of products as "Pb-Free".

**RoHS Exempt:** TI defines "RoHS Exempt" to mean products that contain lead but are compliant with EU RoHS pursuant to a specific EU RoHS exemption.

**Green:** TI defines "Green" to mean the content of Chlorine (Cl) and Bromine (Br) based flame retardants meet JS709B low halogen requirements of <=1000ppm threshold. Antimony trioxide based flame retardants must also meet the <=1000ppm threshold requirement.

(3) MSL, Peak Temp. - The Moisture Sensitivity Level rating according to the JEDEC industry standard classifications, and peak solder temperature.

(4) There may be additional marking, which relates to the logo, the lot trace code information, or the environmental category on the device.

(5) Multiple Device Markings will be inside parentheses. Only one Device Marking contained in parentheses and separated by a "-" will appear on a device. If a line is indented then it is a continuation of the previous line and the two combined represent the entire Device Marking for that device.

(6) Lead finish/Ball material - Orderable Devices may have multiple material finish options. Finish options are separated by a vertical ruled line. Lead finish/Ball material values may wrap to two lines if the finish value exceeds the maximum column width.

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## TAPE AND REEL INFORMATION



\*All dimensions are nominal

| Device             | Package Type | Package Drawing | Pins | SPQ  | Reel Diameter (mm) | Reel Width W1 (mm) | A0 (mm) | B0 (mm) | K0 (mm) | P1 (mm) | W (mm) | Pin1 Quadrant |
|--------------------|--------------|-----------------|------|------|--------------------|--------------------|---------|---------|---------|---------|--------|---------------|
| LM2717MTX-ADJ/NOPB | TSSOP        | PW              | 24   | 2500 | 330.0              | 16.4               | 6.95    | 8.3     | 1.6     | 8.0     | 16.0   | Q1            |

## TAPE AND REEL BOX DIMENSIONS



\*All dimensions are nominal

| Device             | Package Type | Package Drawing | Pins | SPQ  | Length (mm) | Width (mm) | Height (mm) |
|--------------------|--------------|-----------------|------|------|-------------|------------|-------------|
| LM2717MTX-ADJ/NOPB | TSSOP        | PW              | 24   | 2500 | 367.0       | 367.0      | 35.0        |

## TUBE



\*All dimensions are nominal

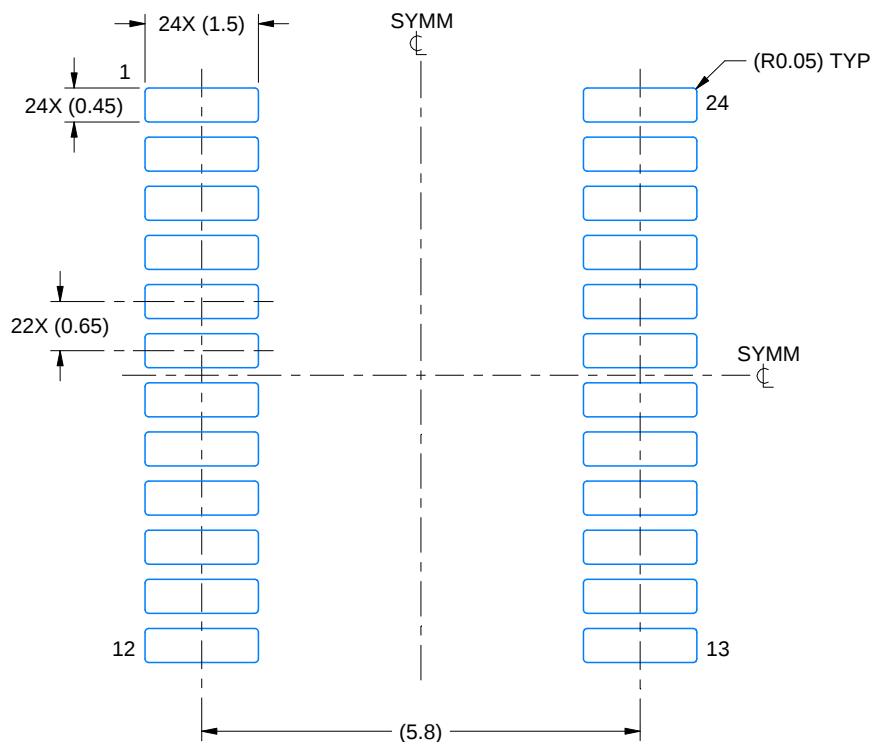
| Device            | Package Name | Package Type | Pins | SPQ | L (mm) | W (mm) | T (μm) | B (mm) |
|-------------------|--------------|--------------|------|-----|--------|--------|--------|--------|
| LM2717MT-ADJ/NOPB | PW           | TSSOP        | 24   | 61  | 495    | 8      | 2514.6 | 4.06   |



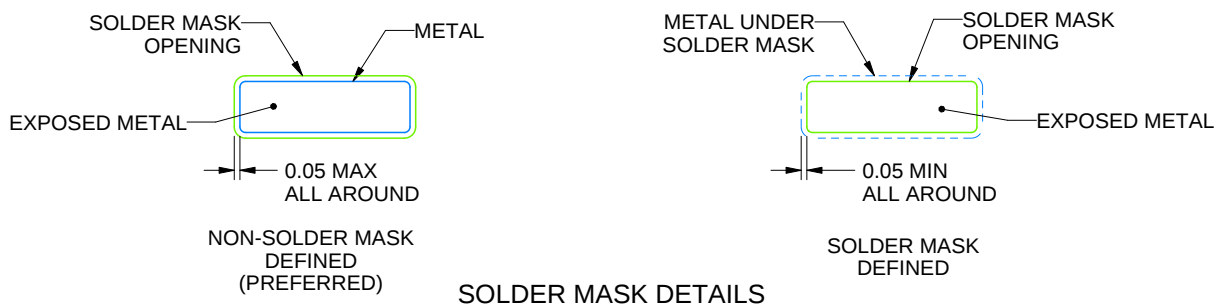
**PW0024A**

## TSSOP - 1.2 mm max height

SMALL OUTLINE PACKAGE



LAND PATTERN EXAMPLE  
EXPOSED METAL SHOWN  
SCALE: 10X



4220208/A 02/2017

NOTES: (continued)

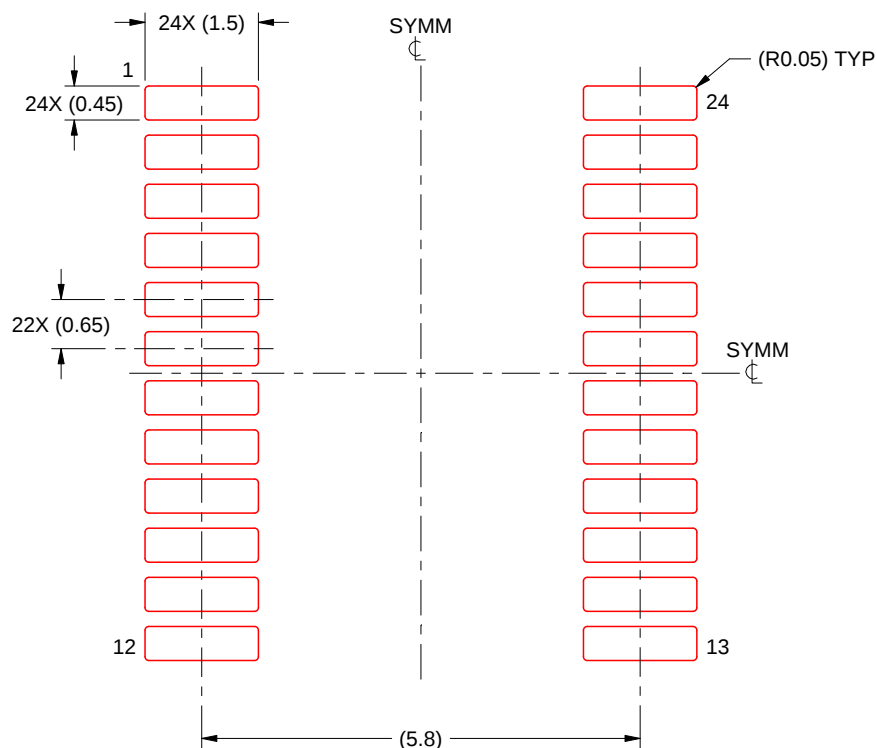
6. Publication IPC-7351 may have alternate designs.  
7. Solder mask tolerances between and around signal pads can vary based on board fabrication site.

# EXAMPLE STENCIL DESIGN

PW0024A

TSSOP - 1.2 mm max height

SMALL OUTLINE PACKAGE



SOLDER PASTE EXAMPLE  
BASED ON 0.125 mm THICK STENCIL  
SCALE: 10X

4220208/A 02/2017

NOTES: (continued)

8. Laser cutting apertures with trapezoidal walls and rounded corners may offer better paste release. IPC-7525 may have alternate design recommendations.
9. Board assembly site may have different recommendations for stencil design.

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